

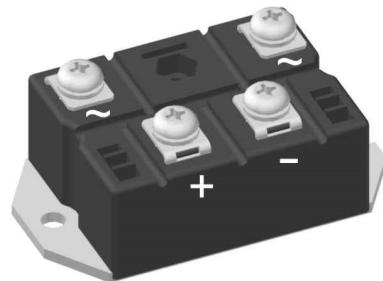
Standard Rectifier Module

| 1~ Rectifier | |
|--------------|----------|
| V_{RRM} | = 1200 V |
| I_{DAV} | = 130 A |
| I_{FSM} | = 1800 A |

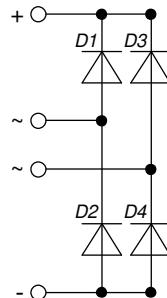
1~ Rectifier Bridge

Part number

VBO130-12NO7



 E72873



Features / Advantages:

- Package with DCB ceramic
- Improved temperature and power cycling
- Planar passivated chips
- Very low forward voltage drop
- Very low leakage current

Applications:

- Diode for main rectification
- For one phase bridge configurations
- Supplies for DC power equipment
- Input rectifiers for PWM inverter
- Battery DC power supplies
- Field supply for DC motors

Package: PWS-E

- Isolation Voltage: 3000 V~
- Industry standard outline
- RoHS compliant
- Easy to mount with two screws
- Base plate: Copper internally DCB isolated
- Advanced power cycling

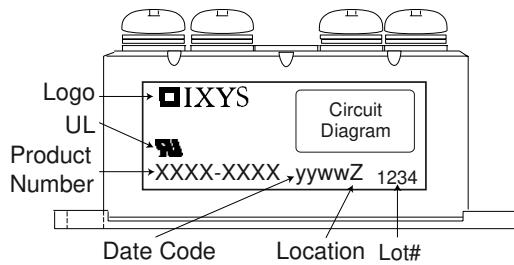
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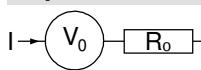
Rectifier

| Symbol | Definition | Conditions | Ratings | | | |
|-------------------|--|--|---|------|----------|---------------|
| | | | min. | typ. | max. | |
| V_{RSM} | max. non-repetitive reverse blocking voltage | $T_{VJ} = 25^\circ C$ | | | 1300 | V |
| V_{RRM} | max. repetitive reverse blocking voltage | $T_{VJ} = 25^\circ C$ | | | 1200 | V |
| I_R | reverse current | $V_R = 1200 \text{ V}$ $V_R = 1200 \text{ V}$ | $T_{VJ} = 25^\circ C$ $T_{VJ} = 150^\circ C$ | | 200 2 | μA mA |
| V_F | forward voltage drop | $I_F = 120 \text{ A}$ | $T_{VJ} = 25^\circ C$ | | 1.10 | V |
| | | $I_F = 240 \text{ A}$ | | | 1.26 | V |
| | | $I_F = 120 \text{ A}$ | $T_{VJ} = 125^\circ C$ | | 1.00 | V |
| | | $I_F = 240 \text{ A}$ | | | 1.21 | V |
| I_{DAV} | bridge output current | $T_C = 110^\circ C$ rectangular | $T_{VJ} = 150^\circ C$ | | 130 | A |
| V_{F0} r_F | threshold voltage slope resistance } for power loss calculation only | | $T_{VJ} = 150^\circ C$ | | 0.77 | V |
| | | | | | 3.4 | $m\Omega$ |
| R_{thJC} | thermal resistance junction to case | | | | 0.5 | K/W |
| R_{thCH} | thermal resistance case to heatsink | | | 0.2 | | K/W |
| P_{tot} | total power dissipation | | $T_C = 25^\circ C$ | | 250 | W |
| I_{FSM} | max. forward surge current | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ | $T_{VJ} = 45^\circ C$ | | 1.80 | kA |
| | | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ | $V_R = 0 \text{ V}$ | | 1.95 | kA |
| | | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ | $T_{VJ} = 150^\circ C$ | | 1.53 | kA |
| | | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ | $V_R = 0 \text{ V}$ | | 1.65 | kA |
| I^2t | value for fusing | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ | $T_{VJ} = 45^\circ C$ | | 16.2 | kA^2s |
| | | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ | $V_R = 0 \text{ V}$ | | 15.7 | kA^2s |
| | | $t = 10 \text{ ms}; (50 \text{ Hz}), \text{sine}$ | $T_{VJ} = 150^\circ C$ | | 11.7 | kA^2s |
| | | $t = 8,3 \text{ ms}; (60 \text{ Hz}), \text{sine}$ | $V_R = 0 \text{ V}$ | | 11.3 | kA^2s |
| C_J | junction capacitance | $V_R = 400 \text{ V}; f = 1 \text{ MHz}$ | $T_{VJ} = 25^\circ C$ | 35 | | pF |

| Package PWS-E | | | Ratings | | | |
|---------------|--|----------------------------------|-------------------------------------|------|------|------|
| Symbol | Definition | Conditions | min. | typ. | max. | Unit |
| I_{RMS} | RMS current | per terminal | | | 200 | A |
| T_{VJ} | virtual junction temperature | | -40 | | 150 | °C |
| T_{op} | operation temperature | | -40 | | 125 | °C |
| T_{stg} | storage temperature | | -40 | | 125 | °C |
| Weight | | | | 273 | | g |
| M_D | mounting torque | | 4.25 | | 5.75 | Nm |
| M_T | terminal torque | | 4.25 | | 5.75 | Nm |
| $d_{Spp/App}$ | creepage distance on surface / striking distance through air | | terminal to terminal | 12.0 | | mm |
| $d_{Spb/Apb}$ | | | terminal to backside | 26.0 | | mm |
| V_{ISOL} | isolation voltage | $t = 1$ second $t = 1$ minute | 50/60 Hz, RMS; $I_{ISOL} \leq 1$ mA | 3000 | | V |
| | | | | 2500 | | V |



| Ordering | Ordering Number | Marking on Product | Delivery Mode | Quantity | Code No. |
|----------|-----------------|--------------------|---------------|----------|----------|
| Standard | VBO130-12NO7 | VBO130-12NO7 | Box | 5 | 474010 |

Equivalent Circuits for Simulation
* on die level
 $T_{VJ} = 150^\circ\text{C}$

Rectifier
 $V_{0\max}$ threshold voltage

0.77

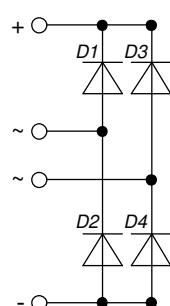
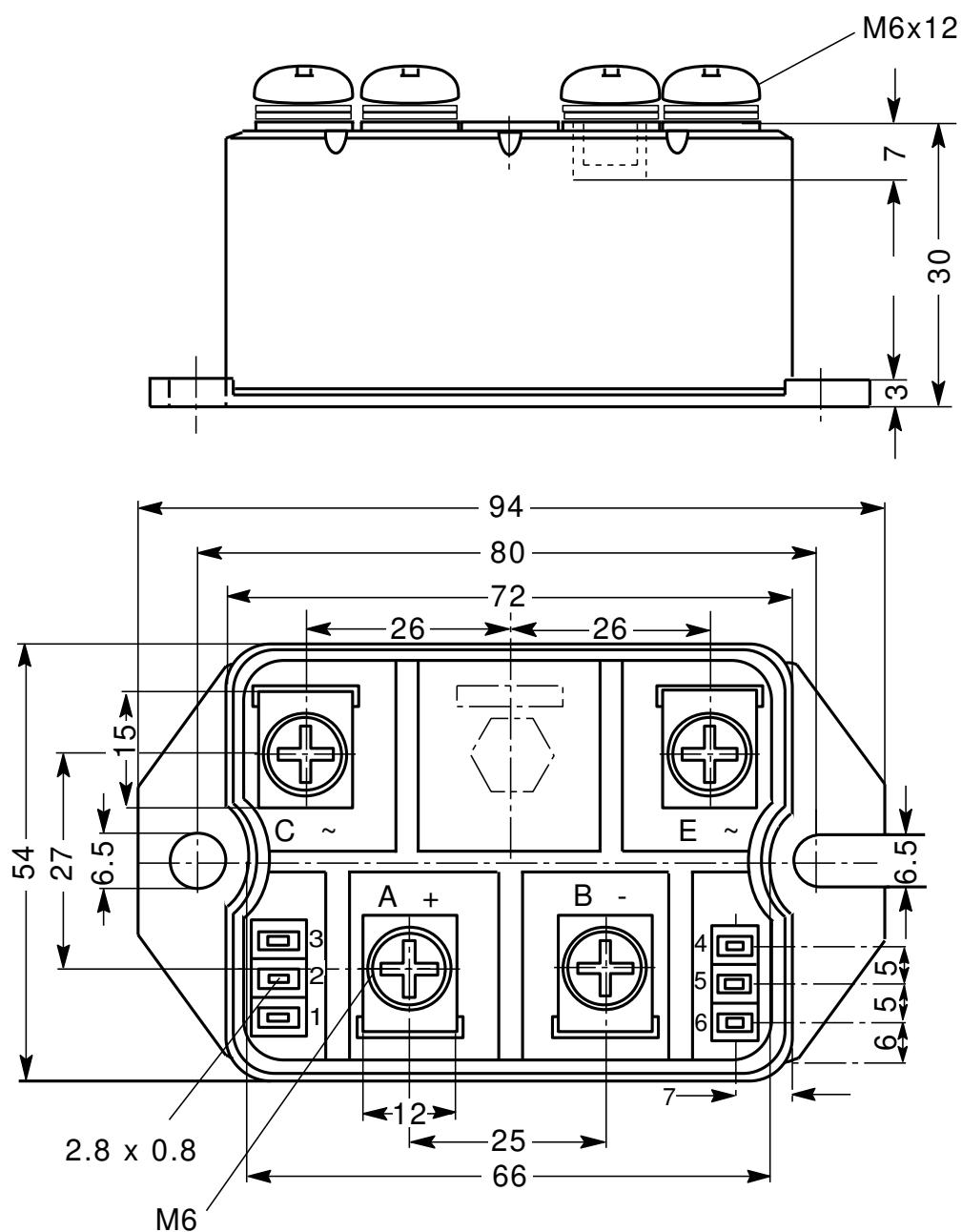
V

 $R_{0\max}$ slope resistance *

2.2

mΩ

Outlines PWS-E



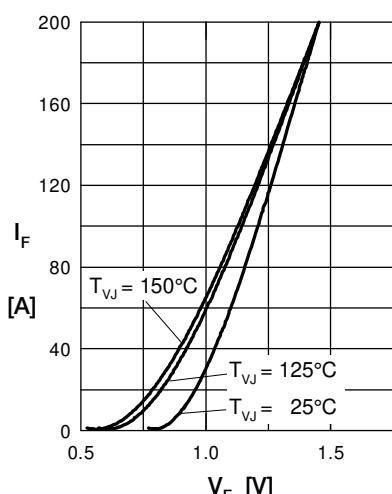
Rectifier


Fig. 1 Forward current vs.
voltage drop per diode

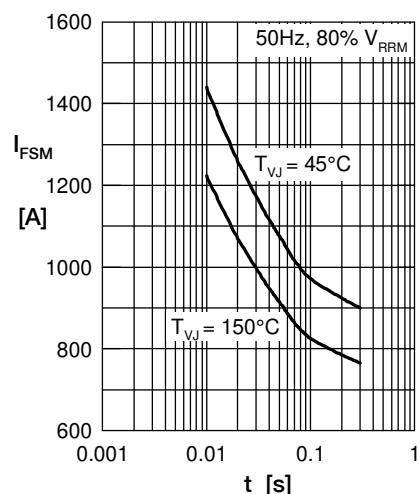


Fig. 2 Surge overload current
vs. time per diode

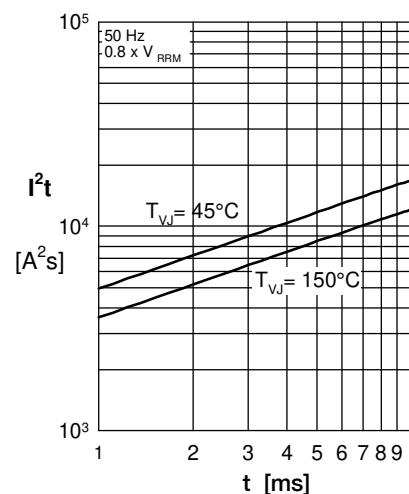


Fig. 3 I^2t vs. time per diode

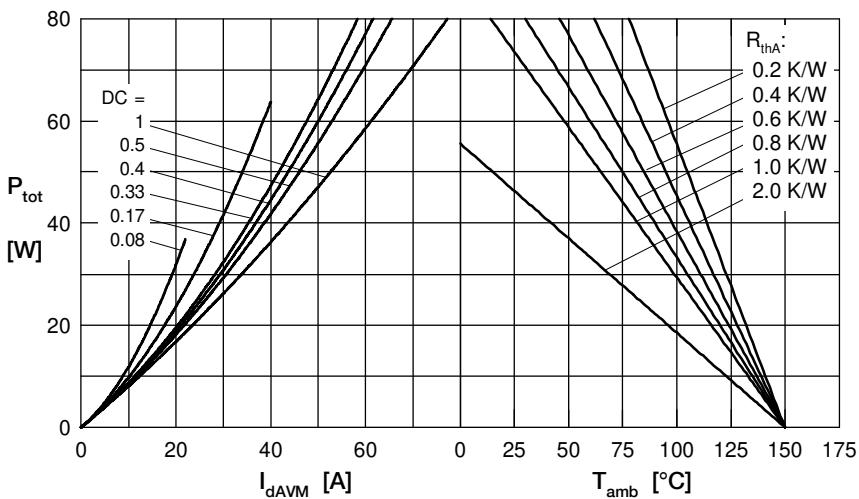


Fig. 4 Power dissipation vs. forward current
and ambient temperature per diode

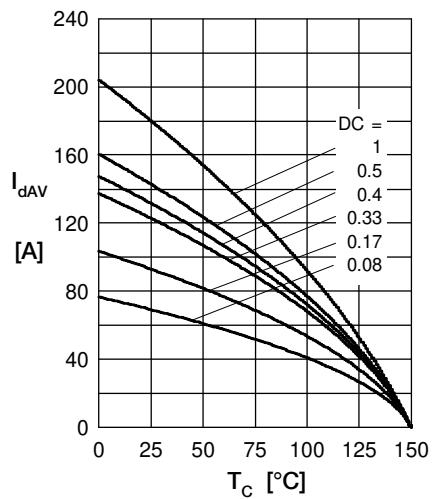
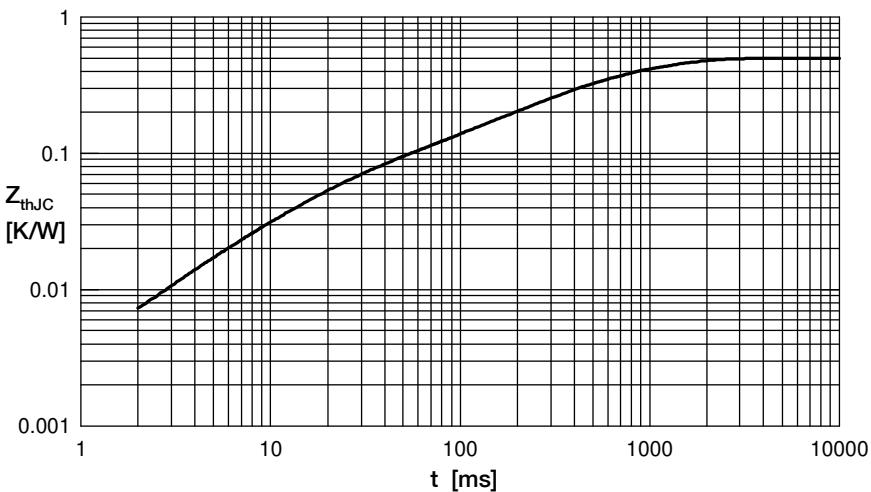


Fig. 5 Max. forward current vs.
case temperature per diode



| R_i | t_i |
|-------|-------|
| 0.050 | 0.02 |
| 0.003 | 0.01 |
| 0.120 | 0.225 |
| 0.217 | 0.8 |
| 0.110 | 0.58 |

Fig. 6 Transient thermal impedance junction to case vs. time per diode

